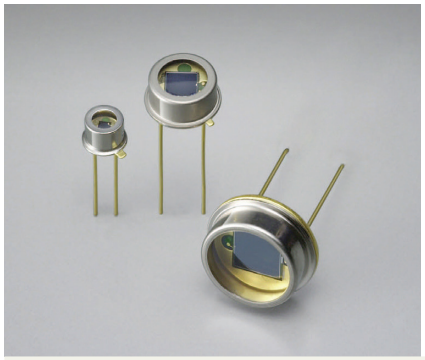
HAMAMATSU
PHOTON IS OUR BUSINESS

Si photodiodes



S1226 series

For UV to visible, precision photometry; suppressed near IR sensitivity

These Si photodiodes have suppressed IR sensitivity. They are suitable for low-light-level detection in analysis and the like.

Features

- **Suppressed near IR sensitivity**
- **High sensitivity in UV region (quartz glass type)**
- **Low dark current**
- **High reliability**

Applications

- **Analytical equipment**
- **Optical measurement equipment, etc.**

Structure / Absolute maximum ratings

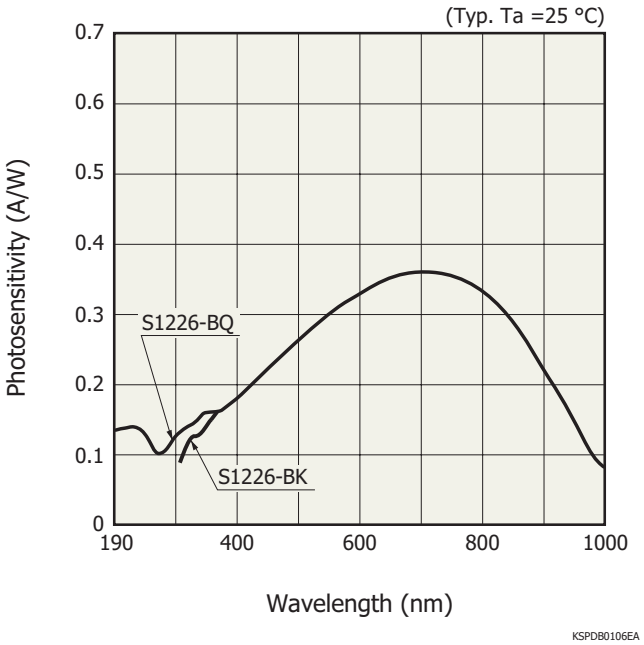
Type no.	Dimensional outline/ Window material*1	Package	Photosensitive area size (mm)	Absolute maximum ratings		
				Reverse voltage V_R max (V)	Operating temperature*2 Topr (°C)	Storage temperature*2 Tstg (°C)
S1226-18BQ*3	(1)/Q	TO-18	1.1 × 1.1	5	-20 to +60	-55 to +80
S1226-18BK	(2)/K				-40 to +100	-55 to +125
S1226-5BQ*3	(3)/Q	TO-5	2.4 × 2.4		-20 to +60	-55 to +80
S1226-5BK	(4)/K				-40 to +100	-55 to +125
S1226-44BQ*3	(5)/Q		3.6 × 3.6		-20 to +60	-55 to +80
S1226-44BK	(6)/K				-40 to +100	-55 to +125
S1226-8BQ*3	(7)/Q	TO-8	5.8 × 5.8		-20 to +60	-55 to +80
S1226-8BK	(8)/K				-40 to +100	-55 to +125

*1: Window material, K=borosilicate glass, Q=quartz glass
*2: No dew condensation
When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation may cause deterioration in characteristics and reliability.
*2: Refer to "Precautions against UV light exposure."
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

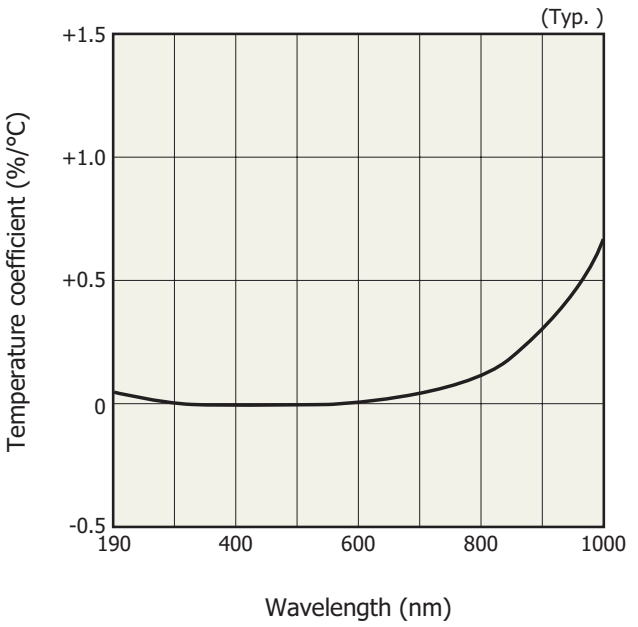
Type no.	Spectral response range λ (nm)	Peak sensitivity wavelength λp (nm)	Photosensitivity S (A/W)				Short circuit current Isc 100 lx		Dark current I_D V_R=10 mV max. (pA)	Temp. coefficient of I_D T_{CID} (times/°C)	Rise time tr V_R=0 V R_L=1 kΩ (μs)	Terminal capacitance Ct V_R=0 V f=10 kHz (pF)	Shunt resistance Rsh V_R=10 mV		Noise equivalent power NEP (W/Hz$^{1/2}$)
			λp	200 nm		He-Ne laser 633 nm	Min. (μA)	Typ. (μA)					Min. (GΩ)	Typ. (GΩ)	
				Min.	Typ.										
S1226-18BQ	190 to 1000	720	0.36	0.10	0.12	0.34	0.5	0.66	2	1.12	0.15	35	5	50	1.6×10^{-15}
S1226-18BK	320 to 1000			-	-										
S1226-5BQ	190 to 1000			0.10	0.12		2.2	2.9	5		0.5	160	2	20	2.5×10^{-15}
S1226-5BK	320 to 1000			-	-										
S1226-44BQ	190 to 1000			0.10	0.12		4.4	5.9	10		1	500	1	10	3.6×10^{-15}
S1226-44BK	320 to 1000			-	-										
S1226-8BQ	190 to 1000			0.10	0.12		12	16	20		2	1200	0.5	5	5.0×10^{-15}
S1226-8BK	320 to 1000			-	-										

Spectral response



KSPDB0106EA

Photosensitivity temperature characteristic



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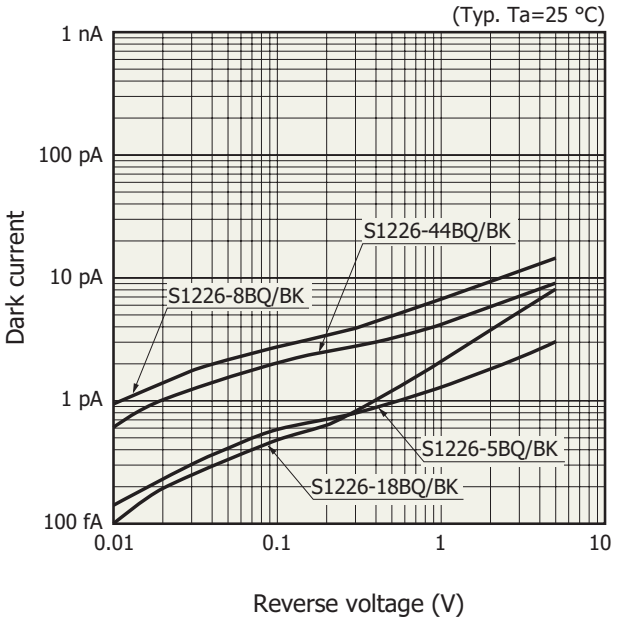
Dark current vs. reverse voltage



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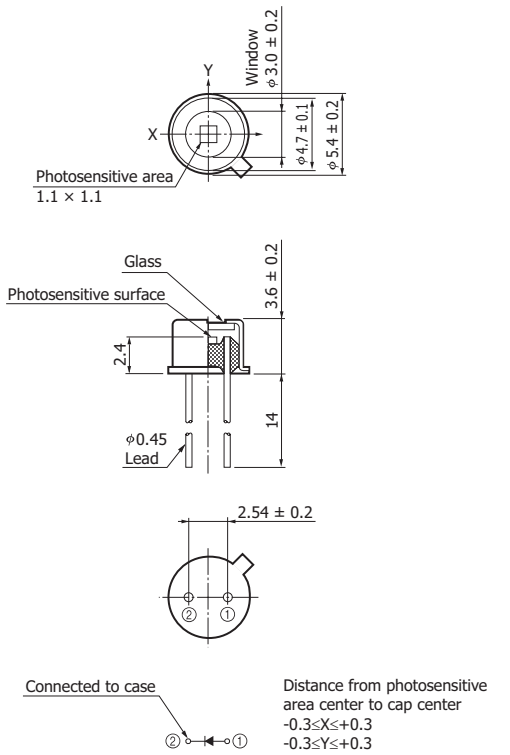
Dimensional outlines (unit: mm)

(1) S1226-18BQ



Distance from photosensitive area center to cap center
-0.3≤X≤+0.3
-0.3≤Y≤+0.3

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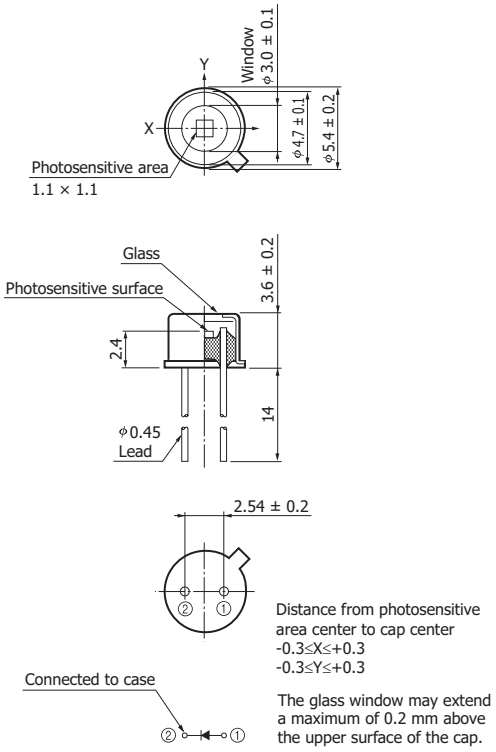
(2) S1226-18BK



Distance from photosensitive area center to cap center
-0.3≤X≤+0.3
-0.3≤Y≤+0.3

The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

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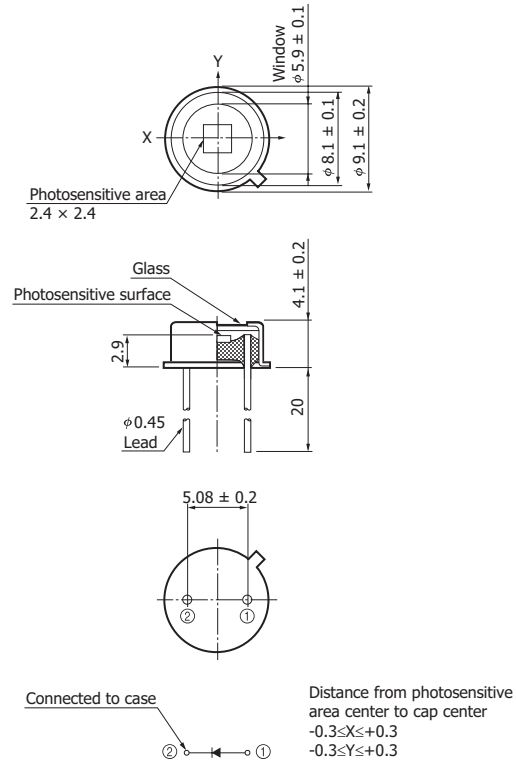
(3) S1226-5BQ



Distance from photosensitive area center to cap center
-0.3≤X≤+0.3
-0.3≤Y≤+0.3

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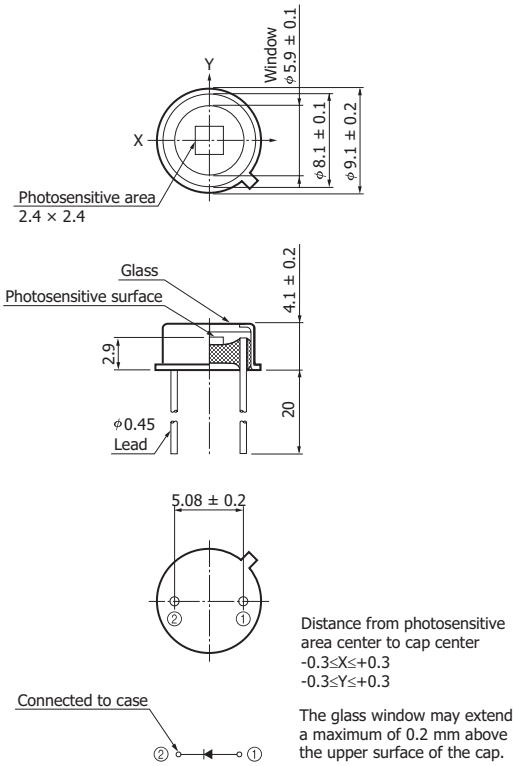
(4) S1226-5BK



Distance from photosensitive area center to cap center
-0.3≤X≤+0.3
-0.3≤Y≤+0.3

The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

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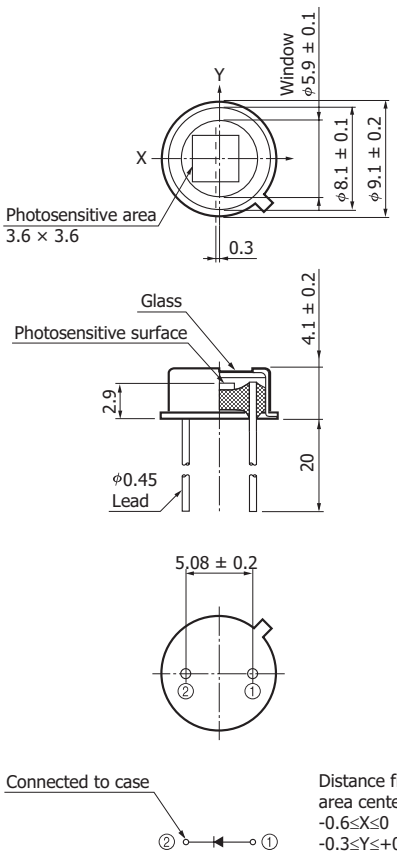
(5) S1226-44BQ



Distance from photosensitive area center to cap center
-0.6≤X≤0
-0.3≤Y≤+0.3

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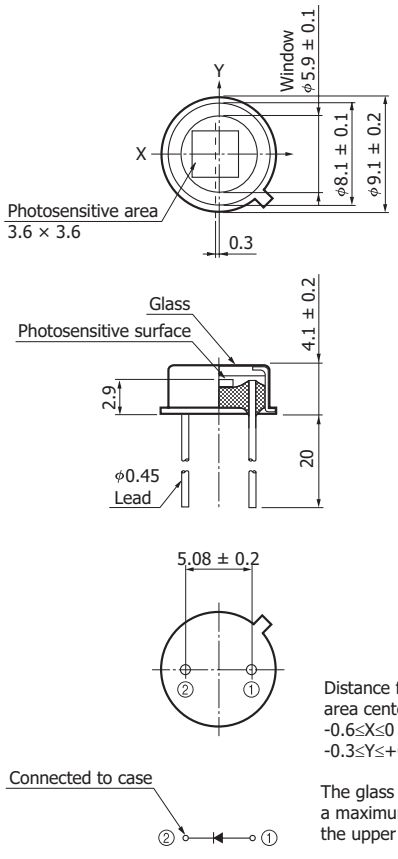
(6) S1226-44BK



Distance from photosensitive area center to cap center
-0.6≤X≤0
-0.3≤Y≤+0.3

The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

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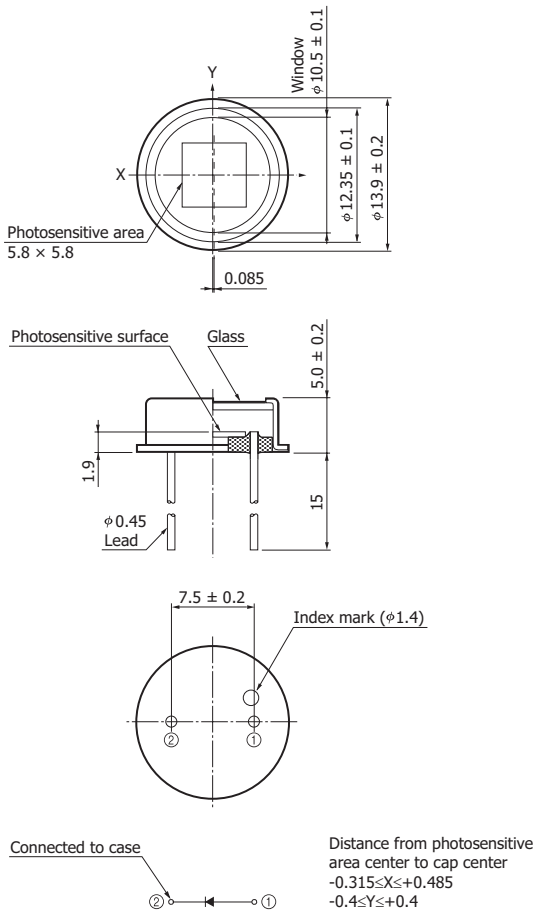
(7) S1226-8BQ



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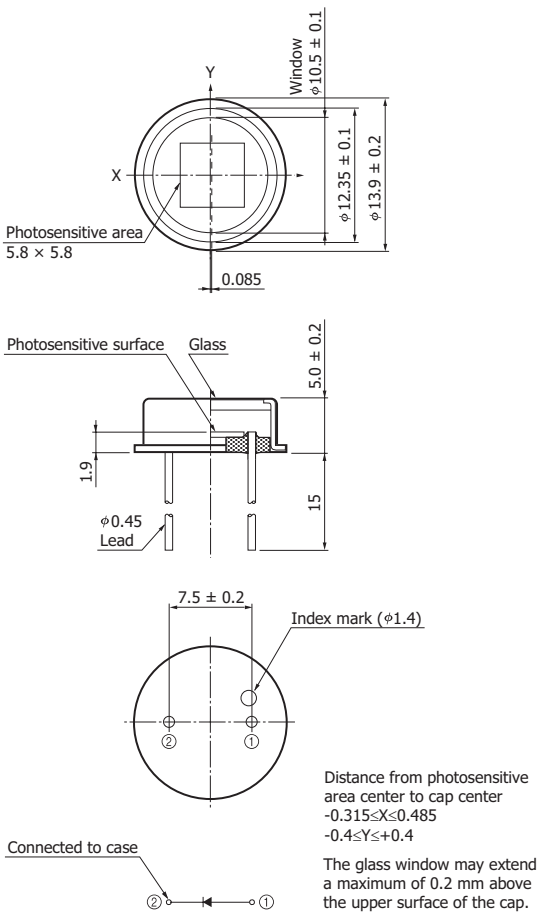
(8) S1226-8BK



KSPDA0115ED

Precautions against UV light exposure

· When UV light irradiation is applied, the product characteristics may degrade. Such examples include degradation of the product's UV sensitivity and increase in dark current. This phenomenon varies depending on the irradiation level, irradiation intensity, usage time, and ambient environment and also varies depending on the product model. Before employing the product, we recommend that you check the tolerance under the ultraviolet light environment that the product will be used in.

· Exposure to UV light may cause the characteristics to degrade due to gas released from the resin bonding the product's component materials. As such, we recommend that you avoid applying UV light directly on the resin and apply it on only the inside of the photosensitive area by using an aperture or the like.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

■ Precautions

· Disclaimer
· Metal, ceramic, plastic package products

■ Technical note

· Si photodiodes

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